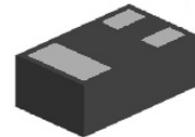


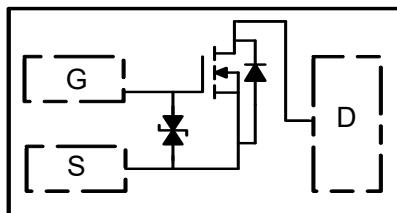
Description

The MOSFET provide the best combination of fast switching, low on-resistance and cost-effectiveness.

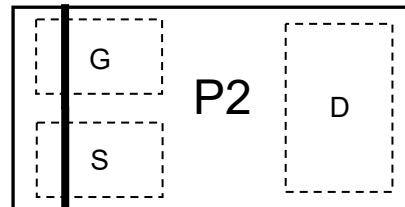
MOSFET Product Summary		
DS(V)	R _{DS(on)} (Ω)	I _D (mA)
20	0.4@ V _{GS} =4.0V	±300
	0.5@ V _{GS} =2.5V	
	0.7@ V _{GS} =1.8V	



DFN1006-3L(Bottom View)



Circuit Diagram



Marking (Top View)

Absolute maximum rating@25°C

Parameter	Symbol	Value	Units
Drain-Source Voltage	V _{DS}	20	V
Gate-Source Voltage	V _{GS}	±8	V
Continuous Drain Current	I _D	±300	mA
Pulsed	I _{DP}	±600	
Total power dissipation	P _D	140	mW
Channel temperature	T _J	150	°C
Range of storage temperature	T _{STG}	-55 to +150	°C

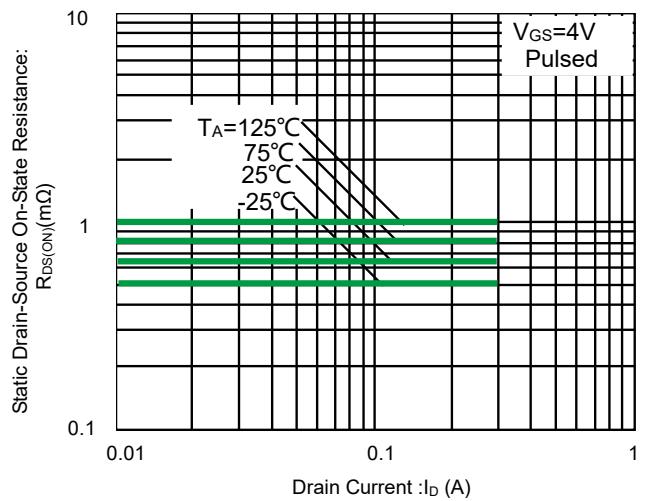
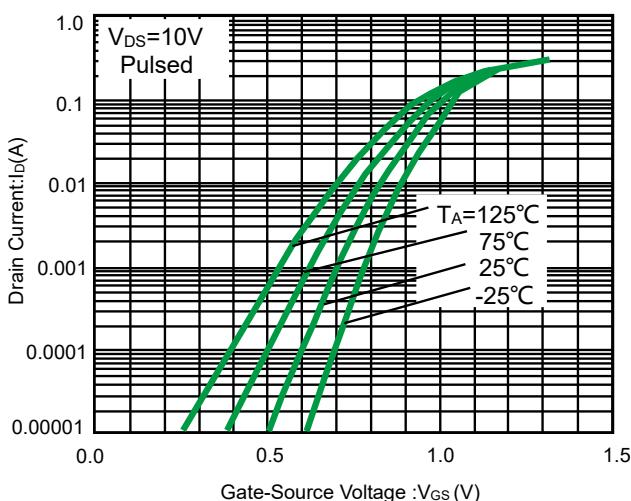
Thermal resistance

Parameter	Symbol	Limits	Units
Channel to ambient	R _{th(ch-a)}	800	°C/W

Electrical characteristics per line@25°C(unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D = 1\text{mA}, V_{GS} = 0\text{V}$	20		-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}$	-	-	1	μA
Gate-Body Leakage Current	I_{GS}	$V_{DS} = 0\text{V}, V_{GS} = \pm 8\text{V}$	-	-	± 10	μA
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	0.5	-	1.1	V
Static Drain-Source On-Resistance	$R_{DS(\text{ON})}$	$V_{GS} = 4.0\text{V}, I_D = 300\text{mA}$	-	0.4	0.7	Ω
		$V_{GS} = 2.5\text{V}, I_D = 200\text{mA}$	-	0.5	0.8	Ω
		$V_{GS} = 1.8\text{V}, I_D = 150\text{mA}$		0.7	1.0	Ω
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 10\text{V}, I_D = 300\text{mA}$	395			ms
Input Capacitance	C_{iss}	$V_{GS} = 0\text{V}, V_{DS} = 10\text{V}, f = 1\text{MHz}$	-	30		pF
Output Capacitance	C_{oss}		-	13		pF
Reverse Transfer Capacitance	C_{rss}		-	13		pF
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 10\text{V}, V_{GS} = 4.0\text{V}, R_G = 10\Omega, R_L = 67\Omega, I_D = 150\text{mA}$	-	7		ns
Turn-Off Delay Time	$t_{d(off)}$		-	23		ns
Turn-On Rise Time	t_r		-	15		ns
Turn-On Fall Time	t_f		-	15		ns
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS} = 0\text{V}, I_S = 100\text{mA}$		-	1.2	V

Typical Characteristics



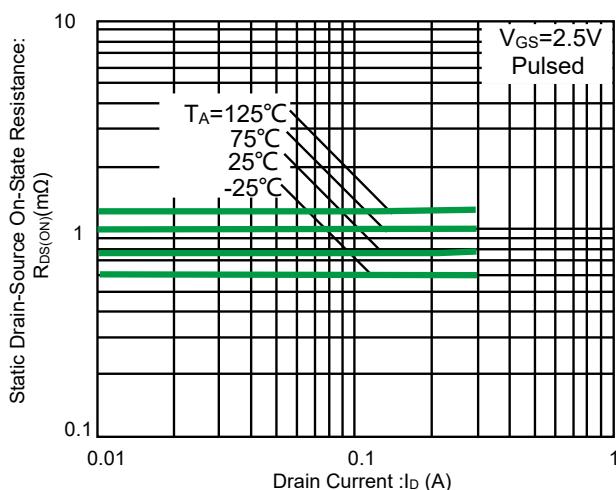


Fig 3. Static drain-source on-state resistance
Vs. drain current (II)

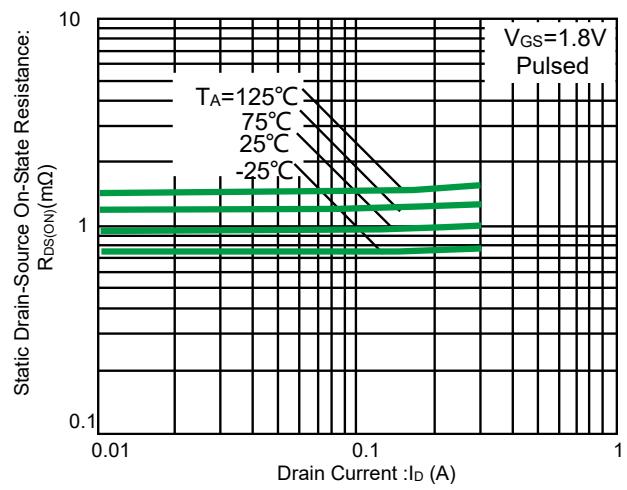


Fig 4. Static drain-source on-state resistance vs.
drain current (III)

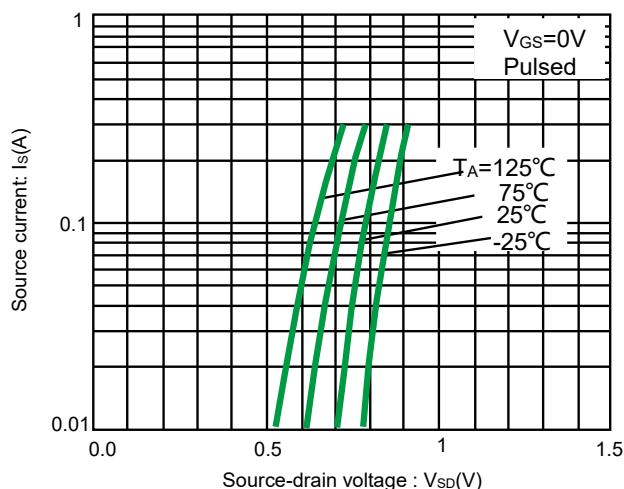


Fig 5. Source current vs. source-drain voltage

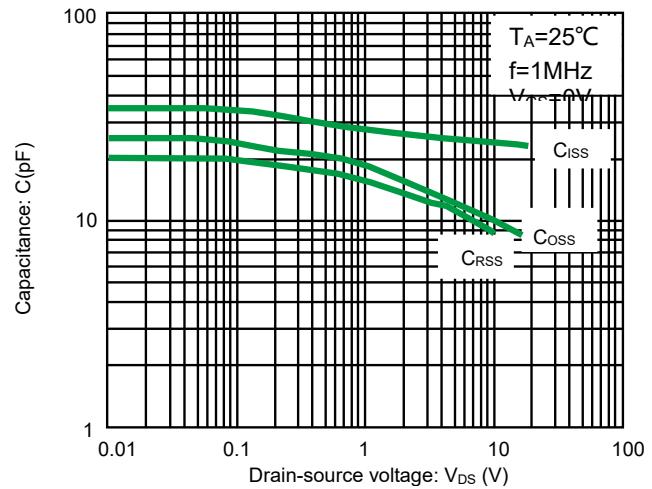


Fig 6. Typical capacitance vs. drain-source voltage

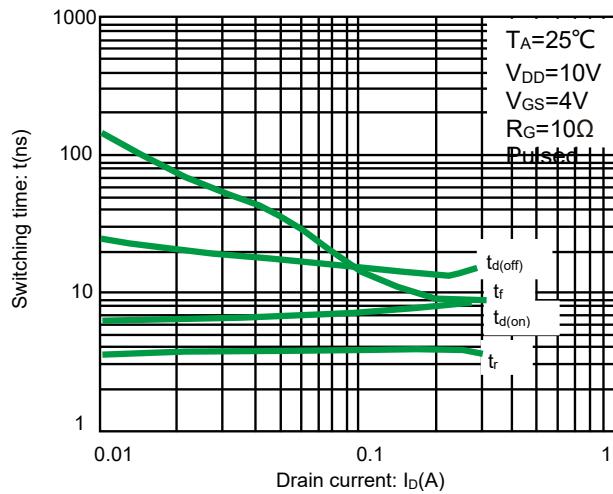


Fig 7. Switching characteristics

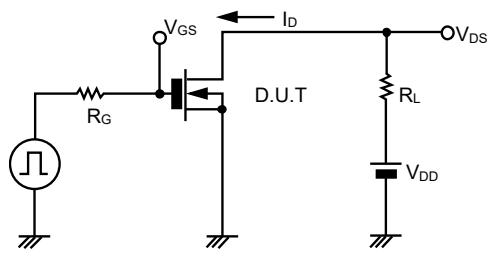
Switching characteristics measurement circuit

Fig.8 Switching time measurement circuit

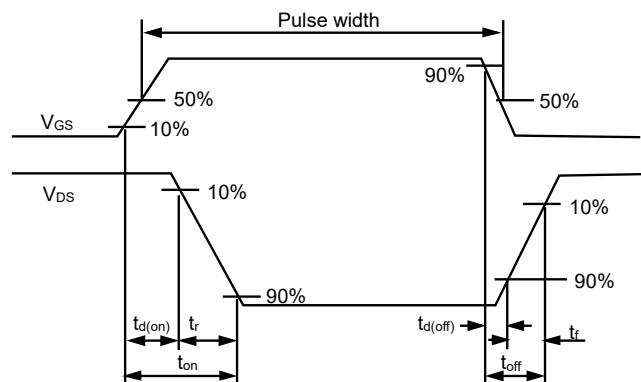
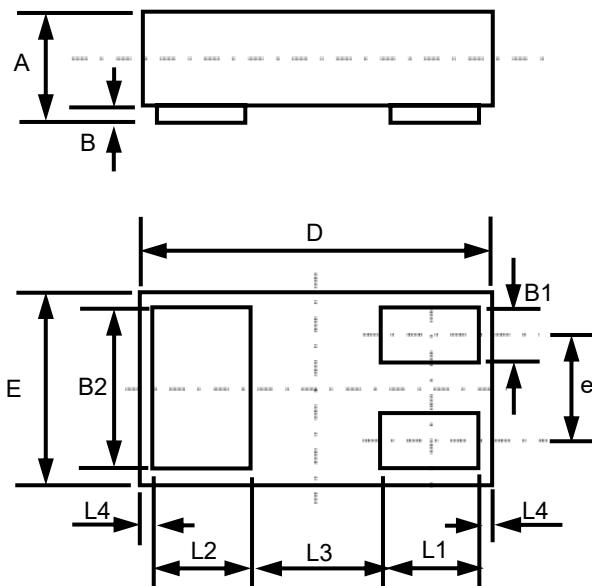
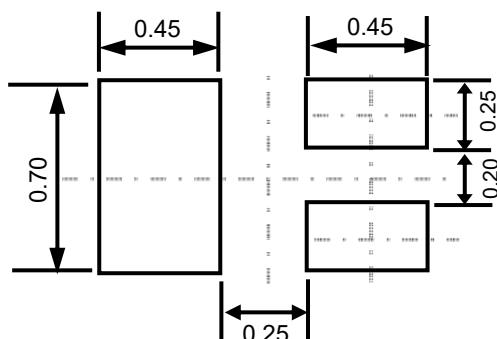


Fig.9 Switching time waveforms

Product dimension (DFN1006-3L)



Dim	Millimeters		
	MIN	Typ	MAX
A	0.33	0.47	0.498
B	0.00	0.03	0.05
B1	0.10	0.15	0.20
B2	0.45	0.50	0.55
D	0.85	1.00	1.15
E	0.45	0.60	0.75
e	--	0.35	--
L1	0.20	0.25	0.30
L2	0.20	0.25	0.30
L3	--	0.39	--
L4	--	0.05	--



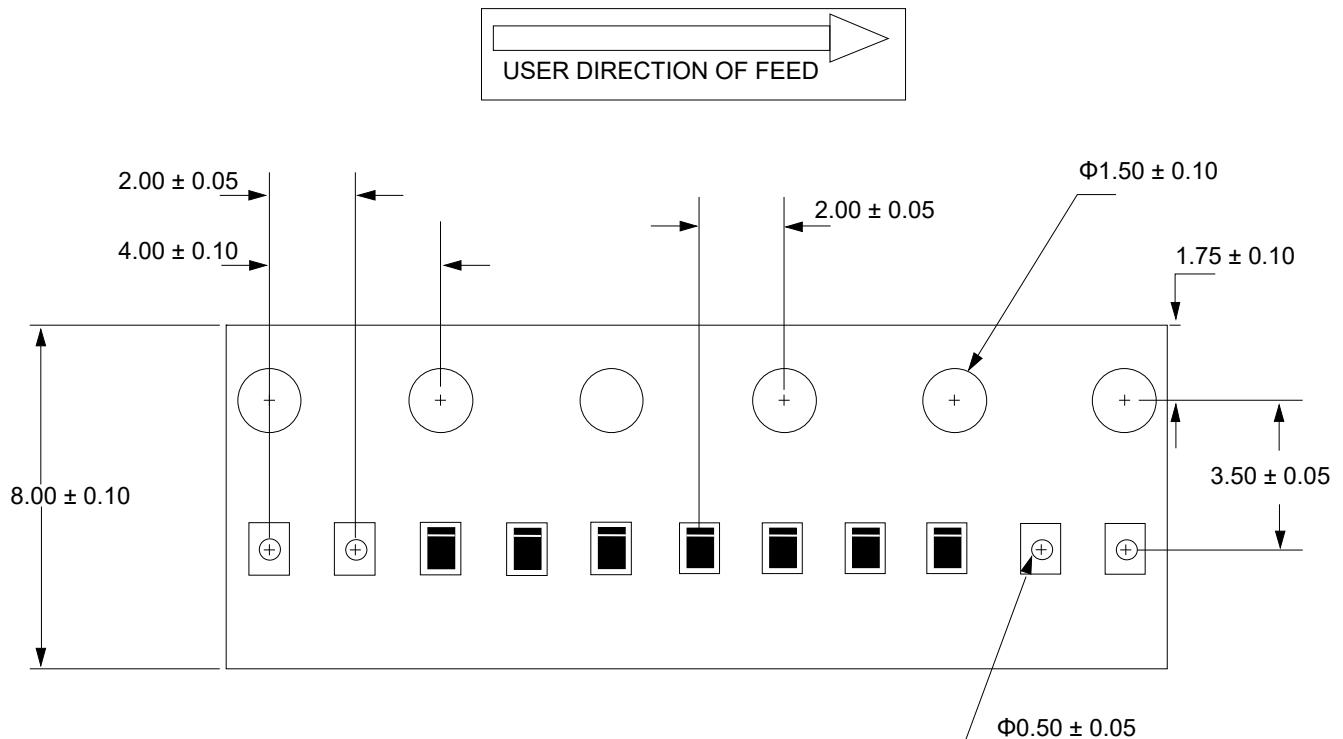
Unit:mm

Suggested PCB Layout

Ordering information

Device	Package	Reel	Shipping
PNM3FD201E0	DFN1006-3L(Pb-Free)	7"	10000 / Tape & Reel

Load with information



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